

Imad Khan

List of Publications by Year in descending order

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51
papers

1,102
citations

394421
19
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all docs

51
docs citations

51
times ranked

689
citing authors

#	ARTICLE	IF	CITATIONS
1	Structural and optoelectronic properties of CsLnZnTe ₃ (Ln= La, Pr, Nd and Sm). Journal of Rare Earths, 2023, 41, 388-396.	4.8	4
2	First-principles prediction of the ground-state crystal structure of double-perovskite halides Cs ₂ AgCrX ₆ (X = Cl, Br, and I). Journal of Physics and Chemistry of Solids, 2022, 160, 110302.	4.0	64
3	Electronic structure and magnetic properties of the perovskites SrTMO ₃ (TM = Mn, Fe, Co, Tc, Ru, Rh.) Tj ETQq1 1 0.784314 rgBT /Overlock 10 T	2.7	21
4	First-principles study of the structural and optoelectronic properties of ANbO ₃ (A = Na, K and Rb) in four crystal phases. Materials Science in Semiconductor Processing, 2022, 139, 106364.	4.0	17
5	Elastic and Optoelectronic Properties of Cs ₂ NaMCl ₆ (M = In, Tl, Sb, Bi). Journal of Electronic Materials, 2021, 50, 456-466.	2.2	33
6	The effect of potassium insertion on optoelectronic properties of cadmium chalcogenides. Materials Science in Semiconductor Processing, 2021, 122, 105466.	4.0	7
7	Spin-orbit coupling effect on the optoelectronic and thermoelectric properties of the perovskites A ₃ SnO (A = Ca, Sr and Ba). Materials Science in Semiconductor Processing, 2021, 132, 105905.	4.0	11
8	Electronic structure, optical and magnetic properties of double Perovskites La ₂ MTiO ₆ (M = Co, Ni, Cu) Tj ETQq0 0 0 rgBT /Overlock 10 T	4.0	15
9	Optoelectronic and elastic properties of metal halides double perovskites Cs ₂ InBiX ₆ (X = F, Cl, Br, I). Chinese Optics Letters, 2021, 19, 030004.	2.9	39
10	Electronic Structure, Mechanical and Magnetic Properties of the Quaternary Perovskites CaA ₃ V ₄ O ₁₂ (A=Mn, Fe, Co, Ni and Cu). Journal of Electronic Materials, 2020, 49, 1230-1242.	2.2	12
11	Electronic structure and magnetic properties of the Mg-rich intermetallic NdNiMg ₅ by hybrid density functional theory. Intermetallics, 2020, 127, 106969.	3.9	1
12	Effects of A-Site cation on the Physical Properties of Quaternary Perovskites AMn ₃ V ₄ O ₁₂ (A= Ca, Ce) Tj ETQq0 0 0 rgBT /Overlock 10 T	4.0	14
13	Theoretical Investigations of Quaternary Semiconductors CsInCdTe ₃ (Ln=La, Pr, Nd and Sm). Journal of Electronic Materials, 2020, 49, 3357-3366.	2.2	16
14	Effects of Ni Substitution on the Electronic Structure and Magnetic Properties of Perovskite SrFeO ₃ . Journal of Electronic Materials, 2020, 49, 3780-3790.	2.2	19
15	First-principles study of BiFeO ₃ and BaTiO ₃ in tetragonal structure. International Journal of Modern Physics B, 2019, 33, 1950231.	2.0	40
16	First principles studies of CsLnCdTe ₃ (Ln= Gd,Tm) for green energy resources. Computational Condensed Matter, 2019, 21, e00427.	2.1	7
17	First-Principles Study of Perovskite Molybdates AMoO ₃ (A=Ca, Sr, Ba). Journal of Electronic Materials, 2019, 48, 1730-1739.	2.2	23
18	First-Principles Study of Electronic Structure, Mechanical, and Thermoelectric Properties of Ternary Palladates CdPd ₃ O ₄ and TiPd ₃ O ₄ . Journal of Electronic Materials, 2018, 47, 1871-1880.	2.2	4

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19	Theoretical studies of the electronic structure and magnetic properties of aluminum-rich intermetallic alloy Al ₁₃ Fe ₄ . International Journal of Modern Physics B, 2018, 32, 1850201.	2.0	4
20	Comparative study of thermoelectric properties of Co based filled antimonide skutterudites with and without SOC effect. Computational Materials Science, 2017, 131, 308-314.	3.0	11
21	Effects of cobalt substitution on the physical properties of the perovskite strontium ferrite. Materials Chemistry and Physics, 2017, 196, 222-228.	4.0	26
22	First-principle studies of the optoelectronic properties of ASnF ₃ (A = Na, K, Rb and Cs). International Journal of Modern Physics B, 2017, 31, 1750148.	2.0	18
23	Structural, Mechanical and Optoelectronic Properties of Y ₂ M ₂ O ₇ (M = Ti, V and Nb) Pyrochlores: A First Principles Study. Journal of Electronic Materials, 2017, 46, 4640-4648.	2.2	5
24	Effects of chemical potential on the thermoelectric performance of alkaline-earth based skutterudites (AFe ₄ Sb ₁₂ , A Ca, Sr and Ba). Journal of Alloys and Compounds, 2017, 694, 253-260.	5.5	10
25	The Influence of Oxygen Substitution on the Optoelectronic Properties of ZnTe. Journal of Chemistry, 2016, 2016, 1-8.	1.9	1
26	Electronic structure of the LiAA ² O ₆ (A=Nb, Ta, and A ² =W, Mo) ceramics by modified Becke-Johnson potential. Optical Materials, 2016, 58, 466-475.	3.6	10
27	First-principle studies of the ternary palladates CaPd ₃ O ₄ and SrPd ₃ O ₄ . Bulletin of Materials Science, 2016, 39, 1861-1870.	1.7	6
28	First-principles studies of pure and fluorine substituted alanines. International Journal of Modern Physics B, 2016, 30, 1650079.	2.0	6
29	Electronic Band Structures of the Highly Desirable III-V Semiconductors: TB-mBJ DFT Studies. Journal of Electronic Materials, 2016, 45, 3314-3323.	2.2	54
30	Thermoelectric studies of IV-VI semiconductors for renewable energy resources. Materials Science in Semiconductor Processing, 2016, 48, 85-94.	4.0	58
31	DFT-mBJ Studies of the Band Structures of the II-VI Semiconductors. Materials Today: Proceedings, 2015, 2, 5122-5127.	1.8	17
32	Electronic band structures of binary skutterudites. Journal of Alloys and Compounds, 2015, 647, 364-369.	5.5	13
33	Theoretical studies of the paramagnetic perovskites MTaO ₃ (M=Ca, Sr and Ba). Materials Chemistry and Physics, 2015, 162, 308-315.	4.0	38
34	Structural and optoelectronic properties of Mg substituted ZTe (Z=Zn, Cd and Hg). Journal of Physics and Chemistry of Solids, 2015, 83, 75-84.	4.0	32
35	Structural and magnetic properties of TiTF ₃ (T=Fe, Co and Ni) by hybrid functional theory. Journal of Magnetism and Magnetic Materials, 2015, 388, 143-149.	2.3	16
36	Structural, Mechanical and Magneto-Electronic Properties of the Ternary Sodium Palladium and Platinum Oxides. Zeitschrift Fur Naturforschung - Section A Journal of Physical Sciences, 2015, 70, 815-822.	1.5	1

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37	Magneto-electronic studies of the inverse-perovskite (Eu ₃ O)In. Journal of Magnetism and Magnetic Materials, 2015, 381, 34-40.	2.3	5
38	First principle studies of structural, elastic, electronic and optical properties of Zn-chalcogenides under pressure. Journal of Semiconductors, 2014, 35, 072001.	3.7	58
39	Magneto-electronic studies of anti-perovskites NiNMn ₃ and ZnNMn ₃ . Computational Materials Science, 2014, 81, 141-145.	3.0	14
40	Density functional studies of magneto-optic properties of CdCoS. Journal of Magnetism and Magnetic Materials, 2014, 351, 60-64.	2.3	10
41	Theoretical studies of the band structure and optoelectronic properties of ZnO _x S _{1-x} . International Journal of Quantum Chemistry, 2013, 113, 1285-1292.	2.0	25
42	Structural and optoelectronic properties of the zinc titanate perovskite and spinel by modified Becke-Johnson potential. Physica B: Condensed Matter, 2013, 420, 54-57.	2.7	44
43	Robust Half-Metallicity and Magnetic Properties of Cubic Perovskite CaFeO ₃ . Chinese Physics Letters, 2013, 30, 047504.	3.3	15
44	First principle optoelectronic studies of visible light sensitive CZT. Superlattices and Microstructures, 2013, 63, 91-99.	3.1	15
45	Electronic band structure of LaCoO ₃ /Y/Mn compounds. Physica B: Condensed Matter, 2013, 410, 112-119.	2.7	11
46	Electronic and optical properties of mixed Be-chalcogenides. Journal of Physics and Chemistry of Solids, 2013, 74, 181-188.	4.0	42
47	Comparison of the electronic band profiles and magneto-optic properties of cubic and orthorhombic SrTbO ₃ . Physica B: Condensed Matter, 2013, 423, 16-20.	2.7	15
48	Conversion of optically isotropic to anisotropic CdS _x Se _{1-x} alloy with S concentration. Computational Materials Science, 2013, 77, 145-152.	3.0	48
49	Electronic structure of cubic perovskite SnTaO ₃ . Intermetallics, 2012, 31, 287-291.	3.9	55
50	Transition from optically inactive to active Mg-chalcogenides: A first principle study. Computational Materials Science, 2012, 61, 278-282.	3.0	27
51	Effect of phase transition on the optoelectronic properties of Zn _{1-x} MgxS. Journal of Applied Physics, 2012, 112, .	2.5	45